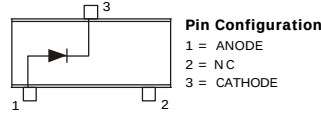
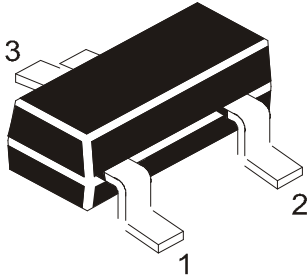


SILICON PLANAR SWITCHING DIODE

BAS16

SOT-23

Formed SMD Package



Marking

BAS16 = A6

High-Speed Switching Diodes

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNIT
Continuous Reverse Voltage	V_R	75	V
Repetitive Peak Reverse Voltage	V_{RRM}	85	V
Forward Current (DC)	I_F	215	mA
Repetitive Peak Forward Current	I_{FRM}	500	mA
Non Repetitive Peak Forward Current (Per Crystal)			
$t=1ms$	I_{FSM}	4.0	A
$t=1ms$	I_{FSM}	1.0	A
$t=1s$	I_{FSM}	0.5	A
Power Dissipation @ $T_a=25^\circ C$	P_D	0.25	W
Storage Temperature Range	T_{stg}	- 55 to +150	$^\circ C$
Junction Temperature	T_j	150	$^\circ C$

Thermal Resistance

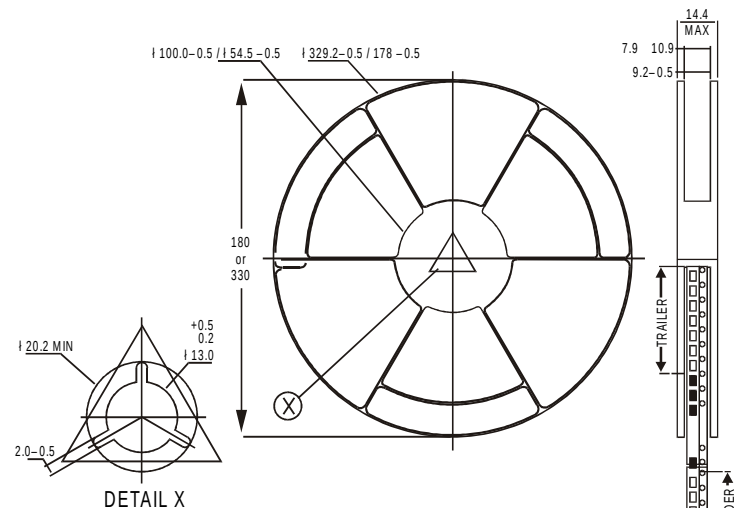
Junction to Ambient in free fair	$R_{th(j-a)}$	500	K/W
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ELECTRICAL CHARACTERISTICS ($T_a=25^\circ C$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Forward Voltage	V_F	$I_F = 1\text{ mA}$ $I_F = 10\text{ mA}$ $I_F = 50\text{ mA}$ $I_F = 150\text{ mA}$			0.715 0.855 1.0 1.25	V V V V
Reverse Voltage Leakage Current	I_R	$V_R=25V, T_j=150^\circ C$ $V_R=75V$ $V_R=75V, T_j=150^\circ C$			30 1.0 50	μA μA μA
Diode Capacitance	C_d	$V_R=0V, f=1MHz$			2.0	pF
Forward Recovery Voltage When Switched to	V_{fr}	$I_F=10mA, t_p=20ns$			1.75	V
Reverse Recovery Time When Switched from	t_{rr}	$I_F=10mA$ to $I_R=60mA, R_L 100\ \Omega$, measured at $I_R=1mA$			4.0	ns
Recovery Charge When Switched from	Q_s	$I_F=10mA$ to $V_R=5V$, $R_L=100\ \Omega$,			45	pC

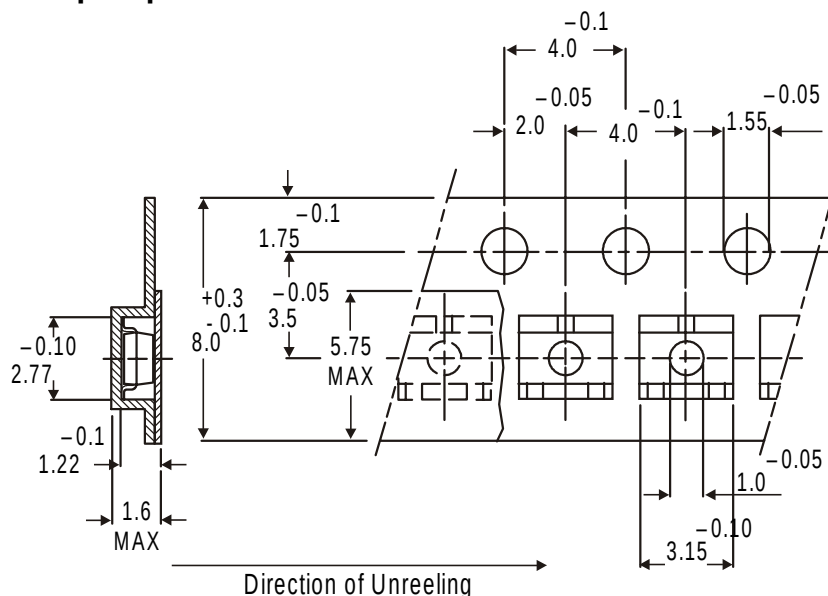
BAS16 Rev_1 270304E

SOT-23 Package Reel Information
Reel specifications for Packing (13"/7" reels)



	8mm Tape	8mm Tape
	Size of Reel	Size of Reel
	330 mm (13")	180 mm (7")
No. of Devices	10,000 Pcs	3,000 Pcs

- ## Tape Specification for SOT-23 Surface Mount Device



Page 2 of 3

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
SOT-23 T&R	3K/reel	136 gm/3K pcs	3" x 7.5" x 7.5"	12.0K	17" x 15" x 13.5"	192.0K	12 kgs
			9" x 9" x 9"	51.0K	19" x 19" x 19"	408.0K	28 kgs
	10K/reel	415 gm/10K pcs	13" x 13" x 0.5"	10.0K	17" x 15" x 13.5"	300.0K	16 kgs

Customer Notes

Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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